# **EPISTAR**

## **ES-AEHRAX10**

AlGaInP AX-series LED Chip

# > Mechanical Specification:

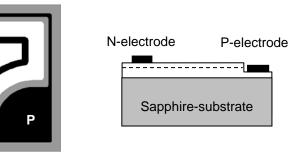
#### (1) Dimension

- Chip size: 10 mil x 10 mil (240  $\pm$  25  $\mu$ m x 240  $\pm$  25  $\mu$ m)

- Thickness: 3.9 mil (100  $\pm$  25  $\mu$ m) - P bonding pad: 3.5 mil (90  $\pm$  10  $\mu$ m) - N bonding pad: 3.5 mil (90  $\pm$  10  $\mu$ m)

#### (2) Metallization

Topside P electrode: Au alloyTopside N electrode: Au alloy



#### **Features:**

- · High luminous intensity
- · Transparent structure
- · Horizontal electrode
- · Non-conductive substrate

#### **Applications:**

- · Outdoor display
- · Traffic signal
- · Consumer Electronic

# > Electro-optical Characteristics at 25°C:

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
- IV II	Vf1		If = 10μA	1.3	-	-	V
Forward Voltage	Vf2		If = 20mA	1.8	-	2.5	V
Reverse Current	Ir		Vr = 10V	-	-	5.0	μΑ
Dominant Wavelength <sup>(1)</sup>	λd		If = 20mA	619	-	629	nm
Spectra Half-width	Δλ		If = 20mA	-	18	-	nm
Luminous Intensity <sup>(2)(3)</sup>	lv	E15	If = 20mA	450	-	-	mcd
		E16		500	-	-	
		E17		550	-	-	

#### Note:

<sup>(1)</sup> Basically, the wavelength span is 10nm; however, customers' special requirements are also welcome.

<sup>(2)</sup> Customers' special requirements are also welcome.

<sup>(3)</sup> Luminous intensity is measured by EPISTAR's equipment on bare chips.

# > Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	If	Ta = 25°C	≤ 30	mA
Reverse Voltage	Vr	Ta = 25°C	≤ 10	V
Junction Temperature	Tj	-	≤ 115	°C
		Chip	-40 ~ +85	°C
Storage Temperature	Tstg	Chip-on-tape/storage	5 ~ 35	°C
		Chip-on-tape/transportation	-20 ~ +65	°C
Temperature during Packaging	-	-	280(<10sec)	°C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Printed Circuit Board (PCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

## > Characteristic Curves:

Fig.1 – Relative luminous Intensity vs. Forward Current

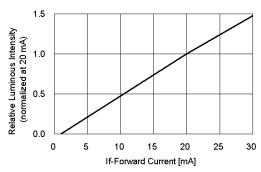


Fig.3 – Relative Intensity (@20mA) vs. Ambient Temperature

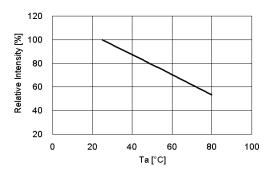


Fig.5 – Dominant Wavelength (@20mA) vs. Ambient Temperature

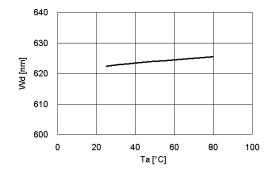


Fig.2 - Forward Current vs. Forward Voltage

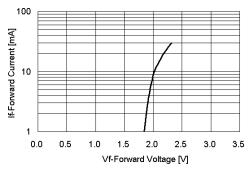
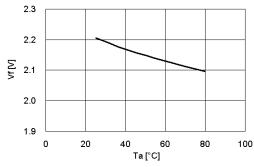


Fig.4 – Forward Voltage (@20mA) vs. Ambient Temperature



**Fig.6** – Maximum Driving Forward DC Current vs. Ambient Temperature (De-rating based on Tj max. = 115°C)

